



6NM70-S

Preliminary

Power MOSFET

6.0A, 700V N-CHANNEL SUPER-JUNCTION MOSFET

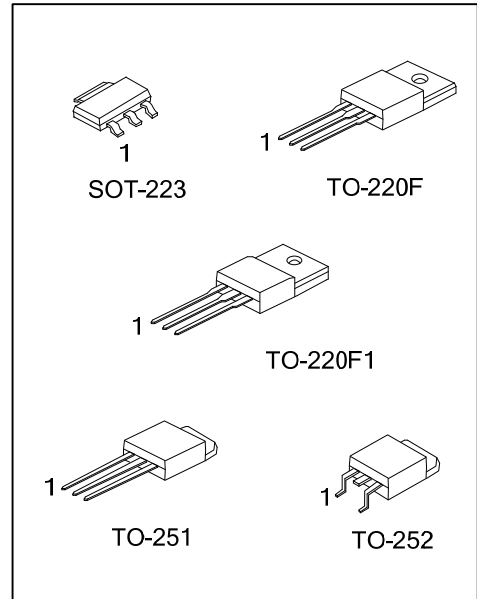
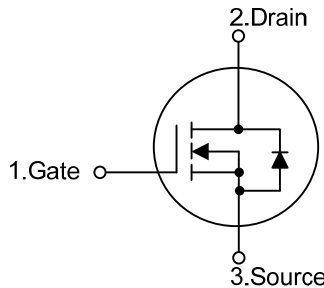
■ DESCRIPTION

The **UTC 6NM70-S** is a Super Junction MOSFET Structure and is designed to have better characteristics, such as fast switching time, low gate charge, low on-state resistance and a high rugged avalanche characteristics. This power MOSFET is usually used at DC-DC, AC-DC converters for power applications.

■ FEATURES

- * $R_{DS(on)} < 1.7\Omega @ V_{GS}=10V, I_D=3.0A$
- * Improved dv/dt capability
- * Fast switching
- * 100% avalanche tested

■ SYMBOL




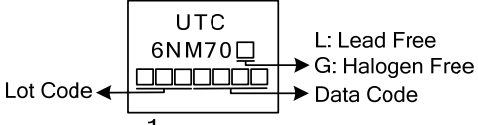
■ ORDERING INFORMATION

Ordering Number		Package	Pin Assignment			Packing
Lead Free	Halogen Free		1	2	3	
-	6NM70G-AA3-R	SOT-223	G	D	S	Tape Reel
6NM70L-TF1-T	6NM70G-TF1-T	TO-220F1	G	D	S	Tube
6NM70L-TF3-T	6NM70G-TF3-T	TO-220F	G	D	S	Tube
6NM70L-TM3-T	6NM70G-TM3-T	TO-251	G	D	S	Tube
6NM70L-TN3-R	6NM70G-TN3-R	TO-252	G	D	S	Tape Reel

Note: Pin Assignment: G: Gate D: Drain S: Source

<p>6NM70G-AA3-R</p> <p>(1)Packing Type</p> <p>(2)Package Type</p> <p>(3)Green Package</p>	<p>(1) T: Tube, R: Tape Reel</p> <p>(2) AA3: SOT-223, TF3: TO-220F, TF1: TO-220F1, TM3: TO-251, TN3: TO-252</p> <p>(3) L: Lead Free, G: Halogen Free and Lead Free</p>
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MARKING

SOT-223	TO-220F / TO-220F1 TO-251 / TO-252
 <p>The diagram shows a rectangular package with the text "6NM70G" at the top. Below it are four small squares representing a data code. A double-headed arrow below the squares is labeled "1". To the left of the package is the text "Lot Code" with an arrow pointing left, and to the right is "Data Code" with an arrow pointing right.</p>	 <p>The diagram shows a rectangular package with "UTC" at the top, "6NM70" below it, and a small square to the right. Below these are five small squares representing a data code. A double-headed arrow below the squares is labeled "1". To the left of the package is the text "Lot Code" with an arrow pointing left, and to the right is "Data Code" with an arrow pointing right. To the right of the package are the following specifications: L: Lead Free G: Halogen Free</p>

■ ABSOLUTE MAXIMUM RATINGS ($T_C = 25^\circ\text{C}$, unless otherwise specified)

PARAMETER		SYMBOL	RATINGS	UNIT
Drain-Source Voltage		V_{DSS}	700	V
Gate-Source Voltage		V_{GSS}	± 30	V
Continuous Drain Current		I_D	6.0	A
Pulsed Drain Current (Note 2)		I_{DM}	24	A
Single Pulsed Avalanche Energy (Note 3)		E_{AS}	132	mJ
Peak Diode Recovery dv/dt (Note 4)		dv/dt	4	V/ns
Power Dissipation	SOT-223	P_D	5	W
	TO-220F/TO-220F1		40	W
	TO-251/TO-252		55	W
Junction Temperature		T_J	+150	$^\circ\text{C}$
Storage Temperature		T_{STG}	-55 ~ +150	$^\circ\text{C}$

Notes: 1. Absolute maximum ratings are those values beyond which the device could be permanently damaged.

Absolute maximum ratings are stress ratings only and functional device operation is not implied.

2. Repetitive Rating: Pulse width limited by maximum junction temperature.

3. $L = 120\text{ mH}$, $I_{AS} = 1.48\text{ A}$, $V_{DD} = 50\text{ V}$, $R_G = 25\Omega$, Starting $T_J = 25^\circ\text{C}$

4. $I_{SD} \leq 6.0\text{ A}$, $di/dt \leq 200\text{ A}/\mu\text{s}$, $V_{DD} \leq BV_{DSS}$, Starting $T_J = 25^\circ\text{C}$

■ THERMAL DATA

PARAMETER		SYMBOL	RATING	UNIT
Junction to Ambient	SOT-223	θ_{JA}	150	$^\circ\text{C}/\text{W}$
	TO-220F/TO-220F1		62.5	
	TO-251/TO-252		110	
Junction to Case	SOT-223	θ_{JC}	25	$^\circ\text{C}/\text{W}$
	TO-220F/TO-220F1		3.13	
	TO-251/TO-252		2.27	

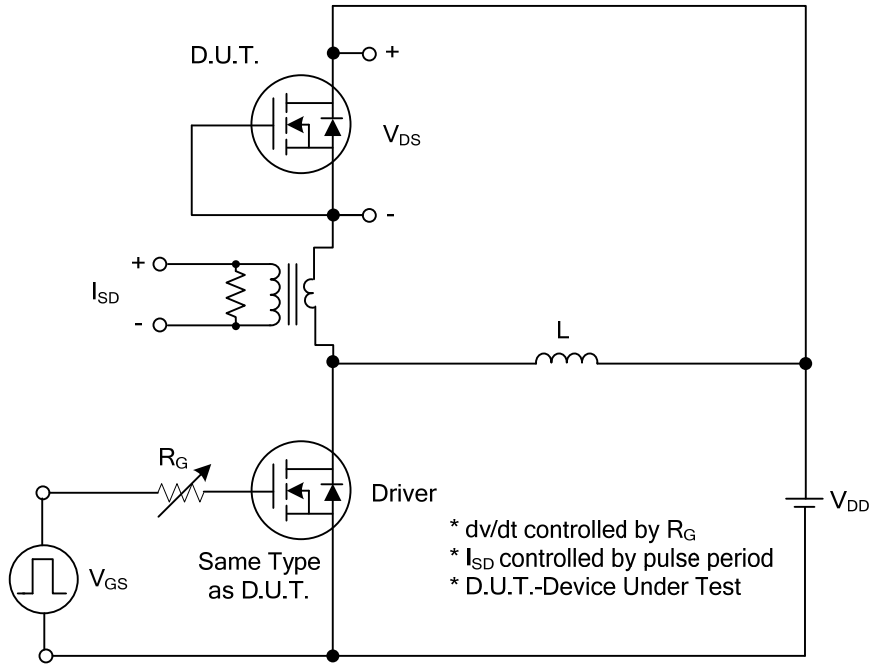
■ ELECTRICAL CHARACTERISTICS ($T_C = 25^\circ\text{C}$, unless otherwise specified)

PARAMETER	SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNIT
OFF CHARACTERISTICS						
Drain-Source Breakdown Voltage	BV_{DSS}	$V_{GS} = 0V, I_D = 250\mu A$	700			V
Drain-Source Leakage Current	I_{DSS}	$V_{DS} = 700V, V_{GS} = 0V$			10	μA
Gate-Source Leakage Current	I_{GSS}	$V_{GS} = 30V, V_{DS} = 0V$			100	nA
		$V_{GS} = -30V, V_{DS} = 0V$			-100	nA
ON CHARACTERISTICS						
Gate Threshold Voltage	$V_{GS(TH)}$	$V_{DS} = V_{GS}, I_D = 250\mu A$	2.5		4.5	V
Static Drain-Source On-State Resistance	$R_{DS(ON)}$	$V_{GS} = 10V, I_D = 3.0A$			1.7	Ω
DYNAMIC CHARACTERISTICS						
Input Capacitance	C_{ISS}	$V_{GS}=0V, V_{DS}=25V, f=1.0MHz$		260		pF
Output Capacitance	C_{OSS}			120		pF
Reverse Transfer Capacitance	C_{RSS}			17		pF
SWITCHING CHARACTERISTICS						
Total Gate Charge (Note 1)	Q_G	$V_{DS}=50V, I_D=1.3A, V_{GS}=10V$ $I_G=100\mu A$ (Note 1,2)		35		nC
Gate-Source Charge	Q_{GS}			1.8		nC
Gate-Drain Charge	Q_{GD}			6.1		nC
Turn-On Delay Time (Note 1)	$t_{D(ON)}$	$V_{DD}=30V, I_D=0.5A, R_G=25\Omega$ (Note 1,2)		47.5		nS
Turn-On Rise Time	t_R			60		nS
Turn-Off Delay Time	$t_{D(OFF)}$			96		nS
Turn-Off Fall Time	t_F			48		nS
DRAIN-SOURCE DIODE CHARACTERISTICS AND MAXIMUM RATINGS						
Maximum Body-Diode Continuous Current	I_S				6	A
Maximum Body-Diode Pulsed Current	I_{SM}				24	A
Drain-Source Diode Forward Voltage (Note 1)	V_{SD}	$I_S=6.0A, V_{GS}=0V$			1.4	V
Reverse Recovery Time (Note 1)	t_{rr}	$I_S=6.0A, V_{GS}=0V,$		410		nS
Reverse Recovery Charge	Q_{rr}	$di_F/dt=100A/\mu s$		3		μC

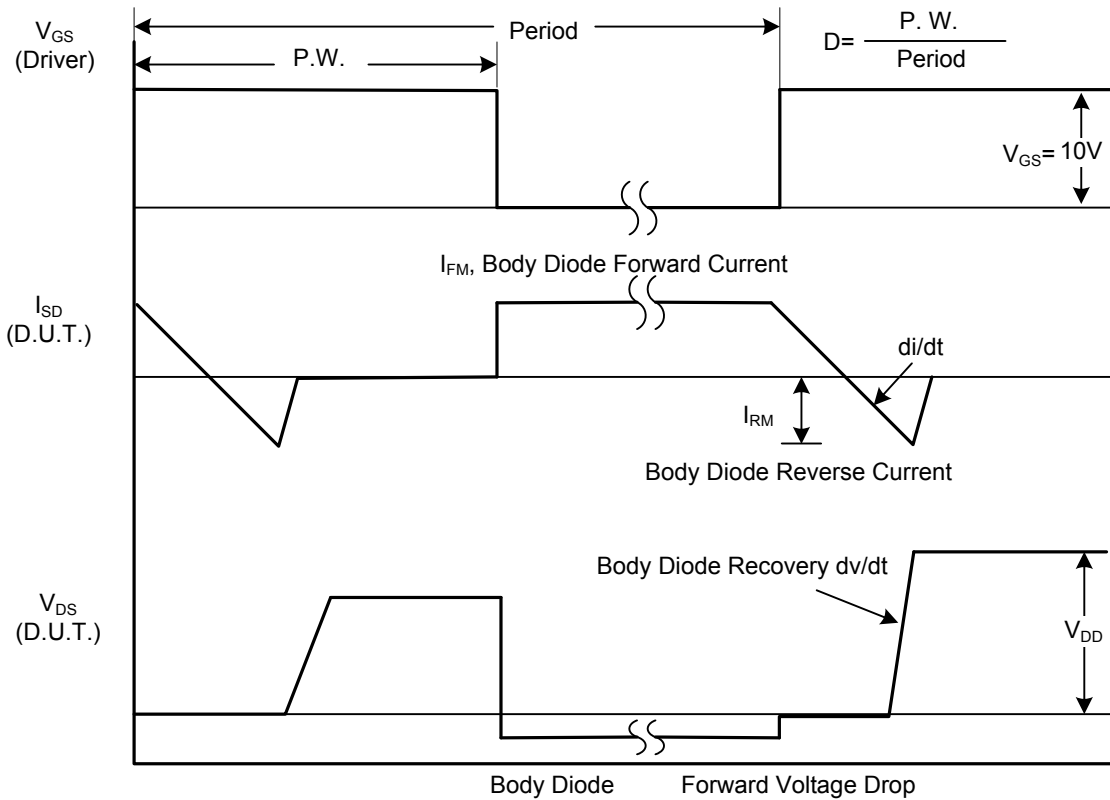
Notes: 1. Pulse Test : Pulse width $\leq 300\mu s$, Duty cycle $\leq 2\%$.

2. Essentially independent of operating ambient temperature.

■ TEST CIRCUITS AND WAVEFORMS

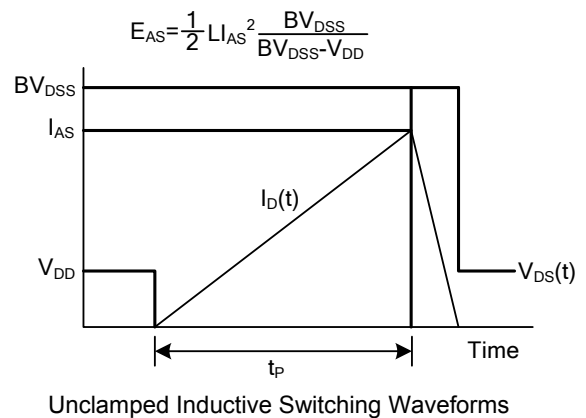
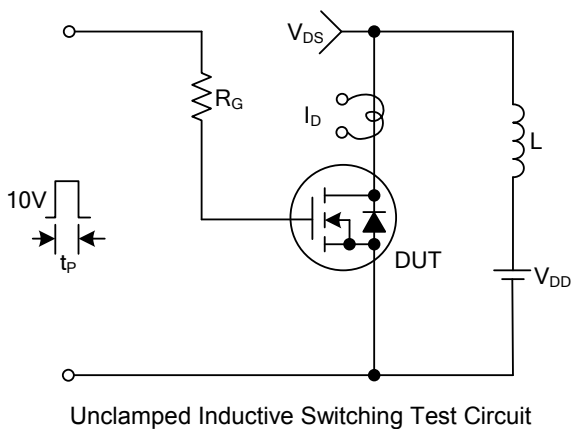
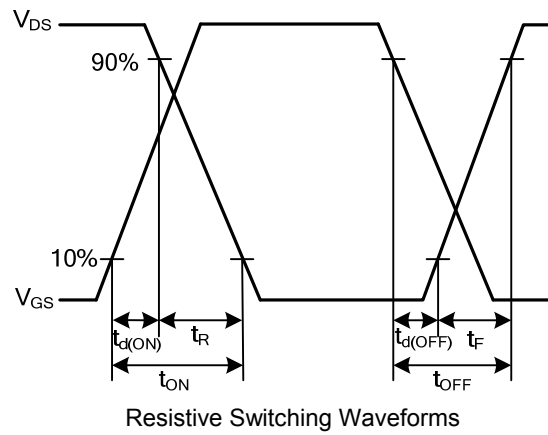
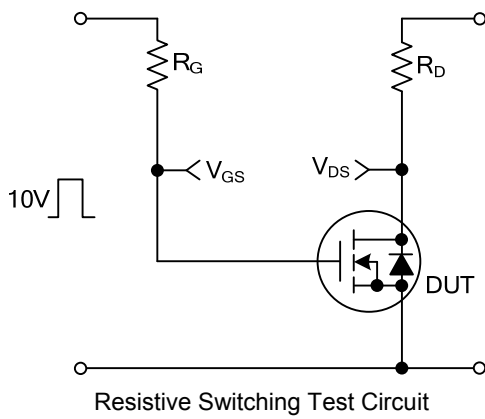
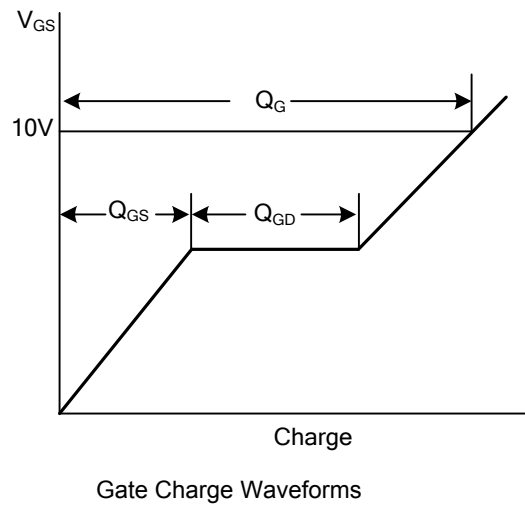
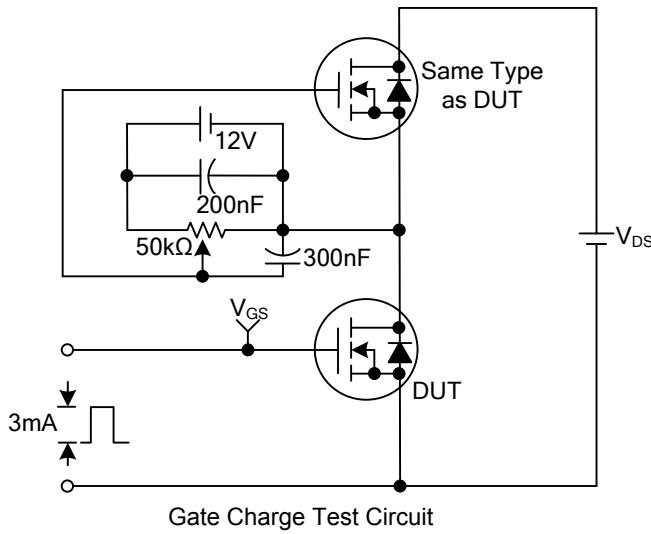


Peak Diode Recovery dv/dt Test Circuit



Peak Diode Recovery dv/dt Waveforms

■ TEST CIRCUITS AND WAVEFORMS (Cont.)



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